

## ADM8690/ADM8691/ADM8692/ADM8693/ADM8695

### FEATURES

Upgrade for ADM690 to ADM695, MAX690 to MAX695  
 Specified over temperature  
 Low power consumption (0.7 mW)  
 Precision voltage monitor  
 Reset assertion down to 1 V  $V_{CC}$   
 Low switch on resistance 0.7  $\Omega$  normal, 7  $\Omega$  in backup  
 High current drive (100 mA)  
 Watchdog timer: 100 ms, 1.6 s, or adjustable  
 400 nA standby current  
 Automatic battery backup power switching  
 Extremely fast gating of chip enable signals (3 ns)  
 Voltage monitor for power fail  
 Available in TSSOP package

### APPLICATIONS

Microprocessor systems  
 Computers  
 Controllers  
 Intelligent instruments  
 Automotive systems

### PRODUCT HIGHLIGHTS

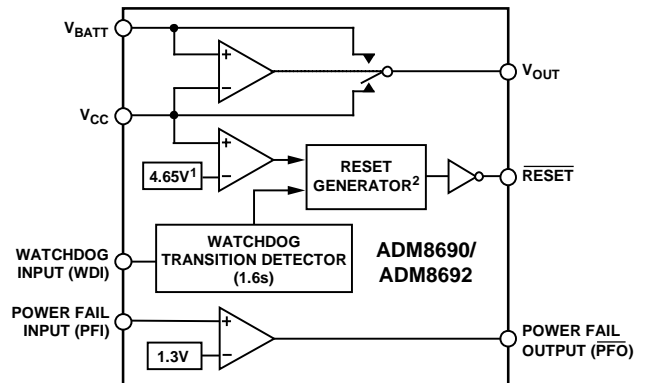
The ADM8690 and ADM8692 are available in 8-lead, PDIP packages and provide:

1. Power-on reset output during power-up, power-down, and brownout conditions. The RESET output remains operational with  $V_{CC}$  as low as 1 V.
2. Battery backup switching for CMOS RAM, CMOS microprocessor, or other low power logic.
3. A reset pulse if the optional watchdog timer has not been toggled within a specified time.
4. A 1.3 V threshold detector for power-fail warning, low battery detection, or to monitor a power supply other than 5 V.

The ADM8691, ADM8693, and ADM8695 are available in 16-lead PDIP and small outline packages (including TSSOP) and provide three additional functions:

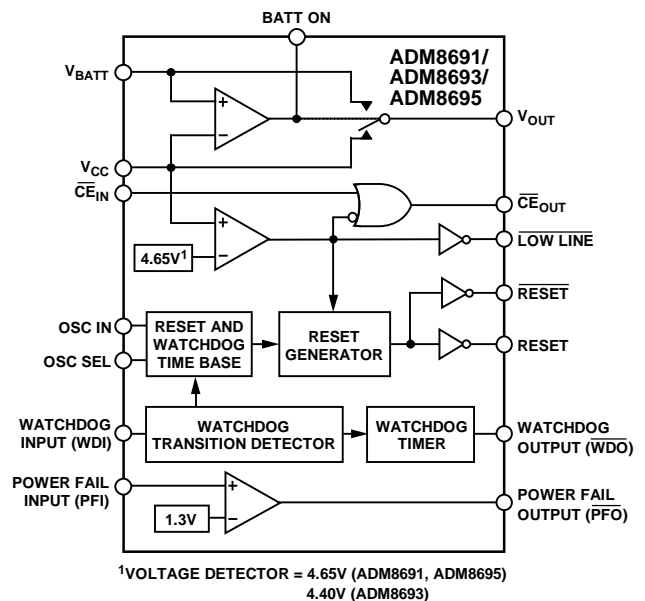
1. Write protection of CMOS RAM or EEPROM.
2. Adjustable reset and watchdog timeout periods.
3. Separate watchdog timeout, backup battery switchover, and low  $V_{CC}$  status outputs.

### FUNCTIONAL BLOCK DIAGRAMS



<sup>1</sup>VOLTAGE DETECTOR = 4.65 V (ADM8690)  
 4.40 V (ADM8692)  
<sup>2</sup>RESET PULSE WIDTH = 50ms (ADM8690, ADM8692)

Figure 1. ADM8690/ADM8692



<sup>1</sup>VOLTAGE DETECTOR = 4.65 V (ADM8691, ADM8695)  
 4.40 V (ADM8693)

Figure 2. ADM8691/ADM8693/ADM8695

### Rev. B

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## REVISION HISTORY

### 6/11—Rev. A to Rev. B

|  |            |
|--|------------|
| Deleted ADM8694.....                             | Throughout |
| Updated Figure 11, Figure 12, and Figure 13..... | 9          |
| Updated Outline Dimensions .....                 | 18         |

### 9/06—Rev. 0 to Rev. A

|   |           |
|---|-----------|
| Updated Format.....                       | Universal |
| Changes to Absolute Maximum Ratings ..... | 6         |
| Updated Ordering Guide.....               | 20        |

### 2/97—Revision 0: Initial Version

## GENERAL DESCRIPTION

The ADM869x family of supervisory circuits offers complete single-chip solutions for power supply monitoring and battery control functions in microprocessor systems. These functions include microprocessor reset, backup battery switchover, watchdog timer, CMOS RAM write protection, and power failure warning. The complete family provides a variety of configurations to satisfy most microprocessor system requirements.

The ADM869x family is fabricated using an advanced epitaxial CMOS process combining low power consumption (0.7 mW),

extremely fast chip enable gating (3 ns), and high reliability.

RESET assertion is guaranteed with  $V_{CC}$  as low as 1 V. In addition, the power switching circuitry is designed for minimal voltage drop thereby permitting increased output current drive of up to 100 mA without the need of an external pass transistor.

See Table 1 for a product selection guide listing the characteristics of each device in the ADM869x family. To place an order, use the Ordering Guide provided as the last section of this data sheet.

**Table 1. Product Selection Guide**

| Part Number | Nominal Reset Time | Nominal $V_{CC}$ Reset Threshold | Nominal Watchdog Timeout Period | Battery Backup Switching | Base Drive Ext PNP | Chip Enable Signals |
|-------------|--------------------|----------------------------------|---------------------------------|--------------------------|--------------------|---------------------|
| ADM8690     | 50 ms              | 4.65 V                           | 1.6 s                           | Yes                      | No                 | No                  |
| ADM8691     | 50 ms or ADJ       | 4.65 V                           | 100 ms, 1.6 s, ADJ              | Yes                      | Yes                | Yes                 |
| ADM8692     | 50 ms              | 4.4 V                            | 1.6 s                           | Yes                      | No                 | No                  |
| ADM8693     | 50 ms or ADJ       | 4.4 V                            | 100 ms, 1.6 s, ADJ              | Yes                      | Yes                | Yes                 |
| ADM8695     | 200 ms or ADJ      | 4.65 V                           | 100 ms, 1.6 s, ADJ              | Yes                      | Yes                | Yes                 |

# ADM8690/ADM8691/ADM8692/ADM8693/ADM8695

## SPECIFICATIONS

$V_{CC}$  = full operating range,  $V_{BATT} = 2.8\text{ V}$ ,  $T_A = T_{MIN}$  to  $T_{MAX}$ , unless otherwise noted.

Table 2.

| Parameter   | Min                | Typ                | Max   | Unit          | Test Conditions/Comments  |
|---|--------------------|--------------------|-------|---------------|---|
| <b>BATTERY BACKUP SWITCHING</b>   |                    |                    |       |               |   |
| $V_{CC}$ Operating Voltage Range  |                    |                    |       |               |   |
| ADM8690, ADM8691, ADM8695   | 4.75               |                    | 5.5   | V             |   |
| ADM8692, ADM8693  | 4.5                |                    | 5.5   | V             |   |
| $V_{BATT}$ Operating Voltage Range                                      |                    |                    |       |               |   |
| ADM8690, ADM8691, ADM8695   | 2.0                |                    | 4.25  | V             |   |
| ADM8692, ADM8693  | 2.0                |                    | 4.0   | V             |   |
| $V_{OUT}$ Output Voltage  | $V_{CC} - 0.005$   | $V_{CC} - 0.0025$  |       | V             | $I_{OUT} = 1\text{ mA}$   |
|   | $V_{CC} - 0.2$     | $V_{CC} - 0.125$   |       | V             | $I_{OUT} \leq 100\text{ mA}$  |
| $V_{OUT}$ in Battery Backup Mode  | $V_{BATT} - 0.005$ | $V_{BATT} - 0.002$ |       | V             | $I_{OUT} = 250\text{ }\mu\text{A}$ , $V_{CC} < V_{BATT} - 0.2\text{ V}$ |
| Supply Current (Excludes $I_{OUT}$ )                                    |                    | 140                | 200   | $\mu\text{A}$ | $I_{OUT} = 100\text{ }\mu\text{A}$                                      |
| Supply Current in Battery Backup Mode                                   |                    | 0.4                | 1     | $\mu\text{A}$ | $V_{CC} = 0\text{ V}$ , $V_{BATT} = 2.8\text{ V}$                       |
| Battery Standby Current   |                    |                    |       |               | $5.5\text{ V} > V_{CC} > V_{BATT} + 0.2\text{ V}$                       |
| + = Discharge, - = Charge   | -0.1               |                    | +0.02 | $\mu\text{A}$ | $T_A = 25^\circ\text{C}$  |
| Battery Switchover Threshold  |                    | 70                 |       | mV            | Power-up  |
| $V_{CC} - V_{BATT}$   |                    | 50                 |       | mV            | Power-down  |
| Battery Switchover Hysteresis   |                    | 20                 |       | mV            |   |
| BATT ON Output Voltage  |                    |                    | 0.3   | V             | $I_{SINK} = 3.2\text{ mA}$  |
| BATT ON Output Short-Circuit Current                                    |                    | 55                 |       | mA            | BATT ON = $V_{OUT} = 4.5\text{ V}$ sink current                         |
|   | 0.5                | 2.5                | 25    | $\mu\text{A}$ | BATT ON = $0\text{ V}$ source current                                   |
| <b>RESET AND WATCHDOG TIMER</b>   |                    |                    |       |               |   |
| Reset Voltage Threshold   |                    |                    |       |               |   |
| ADM8690, ADM8691, ADM8695   | 4.5                | 4.65               | 4.73  | V             |   |
| ADM8692, ADM8693  | 4.25               | 4.4                | 4.48  | V             |   |
| Reset Threshold Hysteresis  |                    | 40                 |       | mV            |   |
| Reset Timeout Delay   |                    |                    |       |               |   |
| ADM8690, ADM8691, ADM8692, ADM8693,                                     | 35                 | 50                 | 70    | ms            | OSC SEL = high  |
| ADM8695   | 140                | 200                | 280   | ms            | OSC SEL = high  |
| Watchdog Timeout Period, Internal Oscillator                            | 1.0                | 1.6                | 2.25  | s             | Long period   |
|   | 70                 | 100                | 140   | ms            | Short period  |
| Watchdog Timeout Period, External Clock                                 | 3840               | 4064               | 4097  | cycles        | Long period   |
|   | 768                | 1011               | 1025  | cycles        | Short period  |
| Minimum WDI Input Pulse Width   | 50                 |                    |       | ns            | $V_{IL} = 0.4$ , $V_{IH} = 3.5\text{ V}$                                |
| $\overline{\text{RESET}}$ Output Voltage @ $V_{CC} = 1\text{ V}$        |                    | 4                  | 20    | mV            | $I_{SINK} = 10\text{ }\mu\text{A}$ , $V_{CC} = 1\text{ V}$              |
| $\overline{\text{RESET}}$ , $\overline{\text{LOW LINE}}$ Output Voltage |                    | 0.05               | 0.4   | V             | $I_{SINK} = 1.6\text{ mA}$ , $V_{CC} = 4.25\text{ V}$                   |
|   | 3.5                |                    |       | V             | $I_{SOURCE} = 1\text{ }\mu\text{A}$                                     |
| $\overline{\text{RESET}}$ , $\overline{\text{WDO}}$ Output Voltage      |                    |                    | 0.4   | V             | $I_{SINK} = 1.6\text{ mA}$  |
|   | 3.5                |                    |       | V             | $I_{SOURCE} = 1\text{ }\mu\text{A}$                                     |
| Output Short-Circuit Source Current                                     | 1                  | 10                 | 25    | $\mu\text{A}$ |   |
| Output Short-Circuit Sink Current                                       |                    | 25                 |       | mA            |   |
| WDI Input Threshold <sup>1</sup>  |                    |                    |       |               |   |
| Logic Low   |                    |                    | 0.8   | V             |   |
| Logic High  | 3.5                |                    |       | V             |   |
| WDI Input Current   |                    | 1                  | 10    | $\mu\text{A}$ | $\text{WDI} = V_{OUT}$  |
|   | -10                | -1                 |       | $\mu\text{A}$ | $\text{WDI} = 0\text{ V}$   |

# ADM8690/ADM8691/ADM8692/ADM8693/ADM8695

| Parameter                                   | Min              | Typ        | Max  | Unit          | Test Conditions/Comments                                 |
|---|------------------|------------|------|---------------|--|
| POWER-FAIL DETECTOR                         |                  |            |      |               |  |
| PFI Input Threshold                         | 1.25             | 1.3        | 1.35 | V             | $V_{CC} = 5\text{ V}$                                    |
| PFI Input Current                           | -25              | $\pm 0.01$ | +25  | nA            |  |
| PFO Output Voltage                          |                  |            | 0.4  | V             | $I_{SINK} = 3.2\text{ mA}$                               |
|   | 3.5              |            |      | V             | $I_{SOURCE} = 1\text{ }\mu\text{A}$                      |
| PFO Short-Circuit Source Current            | 1                | 3          | 25   | $\mu\text{A}$ | PFI = low, $\overline{\text{PFO}} = 0\text{ V}$          |
| PFO Short-Circuit Sink Current              |                  | 25         |      | mA            | PFI = high, $\overline{\text{PFO}} = V_{OUT}$            |
| CHIP ENABLE GATING                          |                  |            |      |               |  |
| $\overline{\text{CE}}_{IN}$ Threshold       |                  |            | 0.8  | V             | $V_{IL}$   |
|   | 3.0              |            |      | V             | $V_{IH}$   |
| $\overline{\text{CE}}_{IN}$ Pull-Up Current |                  | 3          |      | $\mu\text{A}$ |  |
| $\overline{\text{CE}}_{OUT}$ Output Voltage |                  |            | 0.4  | V             | $I_{SINK} = 3.2\text{ mA}$                               |
|   | $V_{OUT} - 1.5$  |            |      | V             | $I_{SOURCE} = 3.0\text{ mA}$                             |
|   | $V_{OUT} - 0.05$ |            |      | V             | $I_{SOURCE} = 1\text{ }\mu\text{A}, V_{CC} = 0\text{ V}$ |
| $\overline{\text{CE}}$ Propagation Delay    |                  | 3          | 7    | ns            |  |
| OSCILLATOR                                  |                  |            |      |               |  |
| OSC IN Input Current                        |                  | $\pm 2$    |      | $\mu\text{A}$ |  |
| OSC SEL Input Pull-Up Current               |                  | 5          |      | $\mu\text{A}$ |  |
| OSC IN Frequency Range                      | 0                |            | 500  | kHz           | OSC SEL = 0 V  |
| OSC IN Frequency with External Capacitor    |                  | 4          |      | kHz           | OSC SEL = 0 V, $C_{OSC} = 47\text{ pF}$                  |

<sup>1</sup> WDI is a three-level input that is internally biased to 38% of  $V_{CC}$  and has an input impedance of approximately 5 M $\Omega$ .

## ABSOLUTE MAXIMUM RATINGS

$T_A = 25^\circ\text{C}$ , unless otherwise noted.

Table 3.

| Parameter                            | Rating                             |
|--------------------------------------|------------------------------------|
| $V_{CC}$                             | –0.3 V to +6 V                     |
| $V_{BATT}$                           | –0.3 V to +6 V                     |
| All Other Inputs                     | –0.3 V to $V_{OUT} + 0.5\text{ V}$ |
| Input Current                        |                                    |
| $V_{CC}$                             | 200 mA                             |
| $V_{BATT}$                           | 50 mA                              |
| GND                                  | 20 mA                              |
| Digital Output Current               | 20 mA                              |
| Power Dissipation, N-8 PDIP          | 400 mW                             |
| $\theta_{JA}$ Thermal Impedance      | 120°C/W                            |
| Power Dissipation, R-8 SOIC          | 400 mW                             |
| $\theta_{JA}$ Thermal Impedance      | 120°C/W                            |
| Power Dissipation, N-16 PDIP         | 600 mW                             |
| $\theta_{JA}$ Thermal Impedance      | 135°C/W                            |
| Power Dissipation, RU-16 TSSOP       | 600 mW                             |
| $\theta_{JA}$ Thermal Impedance      | 158°C/W                            |
| Power Dissipation, R-16 SOIC_N       | 600 mW                             |
| $\theta_{JA}$ Thermal Impedance      | 110°C/W                            |
| Power Dissipation, RW-16 SOIC_W      | 600 mW                             |
| $\theta_{JA}$ Thermal Impedance      | 73°C/W                             |
| Operating Temperature Range          |                                    |
| Industrial (A Version)               | –40°C to +85°C                     |
| Lead Temperature (Soldering, 10 sec) | 300°C                              |
| Storage Temperature Range            | –65°C to +150°C                    |

Stresses above those listed under Absolute Maximum Ratings may cause permanent damage to the device. This is a stress rating only; functional operation of the device at these or any other conditions above those indicated in the operational section of this specification is not implied. Exposure to absolute maximum rating conditions for extended periods may affect device reliability.

### ESD CAUTION



**ESD (electrostatic discharge) sensitive device.** Charged devices and circuit boards can discharge without detection. Although this product features patented or proprietary protection circuitry, damage may occur on devices subjected to high energy ESD. Therefore, proper ESD precautions should be taken to avoid performance degradation or loss of functionality.

## PIN CONFIGURATIONS AND FUNCTION DESCRIPTIONS

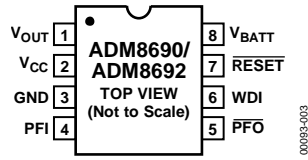


Figure 3. ADM8690 and ADM8692, Pin Configuration

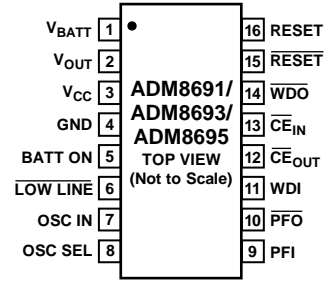


Figure 4. ADM8691, ADM8693, and ADM8695 Pin Configuration

Table 4. Pin Function Descriptions

| Mnemonic          | Function  |
|-------------------|---|
| V <sub>CC</sub>   | Power Supply Input. 5 V nominal.  |
| V <sub>BATT</sub> | Backup Battery Input.   |
| V <sub>OUT</sub>  | Output Voltage. V <sub>CC</sub> or V <sub>BATT</sub> is internally switched to V <sub>OUT</sub> , depending on which is at the highest potential. V <sub>OUT</sub> can supply up to 100 mA to power CMOS RAM. Connect V <sub>OUT</sub> to V <sub>CC</sub> if V <sub>OUT</sub> and V <sub>BATT</sub> are not used.   |
| GND               | Ground. This is the 0 V ground reference for all signals.   |
| RESET             | Logic Output. RESET goes low if V <sub>CC</sub> falls below the reset threshold, or the watchdog timer is not serviced within its timeout period. The reset threshold is typically 4.65 V for the ADM8690/ADM8691/ADM8695 and 4.4 V for the ADM8692 and ADM8693. RESET remains low for 50 ms (ADM8690/ADM8691/ADM8692/ADM8693) or 200 ms (ADM8695) after V <sub>CC</sub> returns above the threshold. RESET also goes low for 50 ms (ADM8690/ADM8691/ADM8692/ADM8693) or 200 ms (ADM8695) if the watchdog timer is enabled but not serviced within its timeout period. The RESET pulse width can be adjusted on the ADM8691/ADM8693/ADM8695, as shown in Table 5. The RESET output has an internal 3 $\mu$ A pull-up, and can either connect to an open collector reset bus or directly drive a CMOS gate without an external pull-up resistor. |
| WDI               | Watchdog Input. WDI is a three-level input. If WDI remains either high or low for longer than the watchdog timeout period, RESET pulses low and WDO goes low. The timer resets with each transition on the WDI line. The watchdog timer can be disabled if WDI is left floating or is driven to midsupply.  |
| PFI               | Power-Fail Input. PFI is the noninverting input to the power-fail comparator. When PFI is less than 1.3 V, PFO goes low. Connect PFI to GND or V <sub>OUT</sub> when not used.  |
| PFO               | Power-Fail Output. PFO is the output of the power-fail comparator. It goes low when PFI is less than 1.3 V. The comparator is turned off and PFO goes low when V <sub>CC</sub> is below V <sub>BATT</sub> .   |
| CE <sub>IN</sub>  | Logic Input. The input to the CE gating circuit. When not in use, connect this pin to GND or V <sub>OUT</sub> .   |
| CE <sub>OUT</sub> | Logic Output. CE <sub>OUT</sub> is a gated version of the CE <sub>IN</sub> signal. CE <sub>OUT</sub> tracks CE <sub>IN</sub> when V <sub>CC</sub> is above the reset threshold. If V <sub>CC</sub> is below the reset threshold, CE <sub>OUT</sub> is forced high. See Figure 21 and Figure 22.   |
| BATT ON           | Logic Output. BATT ON goes high when V <sub>OUT</sub> is internally switched to the V <sub>BATT</sub> input. It goes low when V <sub>OUT</sub> is internally switched to V <sub>CC</sub> . The output typically sinks 35 mA and can directly drive the base of an external PNP transistor to increase the output current above the 100 mA rating of V <sub>OUT</sub> .  |
| LOW LINE          | Logic Output. LOW LINE goes low when V <sub>CC</sub> falls below the reset threshold. It returns high as soon as V <sub>CC</sub> rises above the reset threshold.   |
| RESET             | Logic Output. RESET is an active high output. It is the inverse of RESET.   |
| OSC SEL           | Logic Oscillator Select Input. When OSC SEL is unconnected (floating) or driven high, the internal oscillator sets the reset active time and watchdog timeout period. When OSC SEL is low, the external oscillator input, OSC IN, is enabled. OSC SEL has a 3 $\mu$ A internal pull-up (see Table 5).   |
| OSC IN            | Oscillator Logic Input. With OSC SEL low, OSC IN can be driven by an external clock signal or an external capacitor can be connected between OSC IN and GND. This sets both the reset active pulse timing and the watchdog timeout period (see Table 5 and Figure 17, Figure 18, Figure 19, and Figure 20). With OSC SEL high or floating, the internal oscillator is enabled and the reset active time is fixed at 50 ms typical (ADM8691/ADM8693) or 200 ms typical (ADM8695). In this mode, the OSC IN pin selects between fast (100 ms) and slow (1.6 s) watchdog timeout periods. In both modes, the timeout period immediately after a reset is 1.6 s typical.  |
| WDO               | Logic Output. The watchdog output, WDO, goes low if WDI remains either high or low for longer than the watchdog timeout period. WDO is set high by the next transition at WDI. If WDI is unconnected or at midsupply, the watchdog timer is disabled and WDO remains high. WDO also goes high when LOW LINE goes low.   |

## TYPICAL PERFORMANCE CHARACTERISTICS

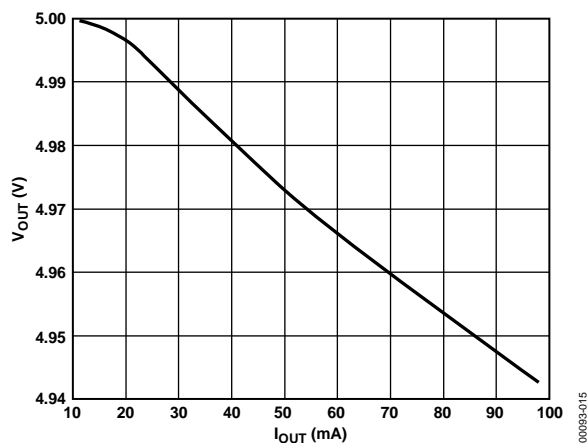


Figure 5.  $V_{OUT}$  vs.  $I_{OUT}$  Normal Operation

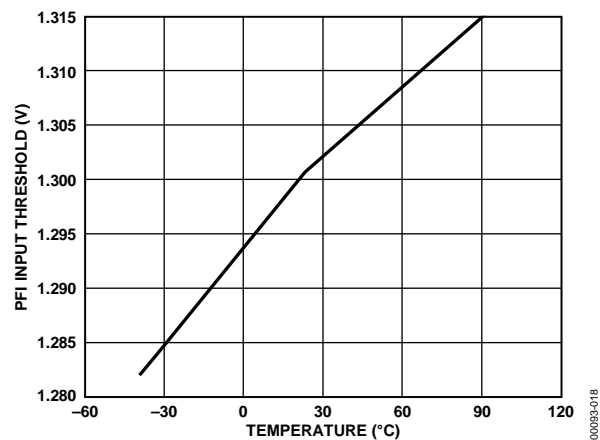


Figure 8. PFI Input Threshold vs. Temperature

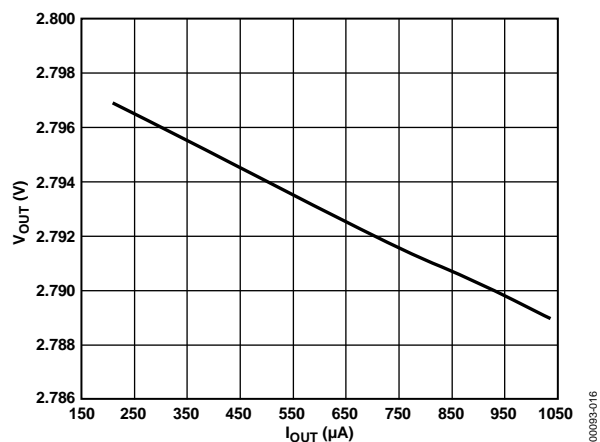


Figure 6.  $V_{OUT}$  vs.  $I_{OUT}$  Battery Backup

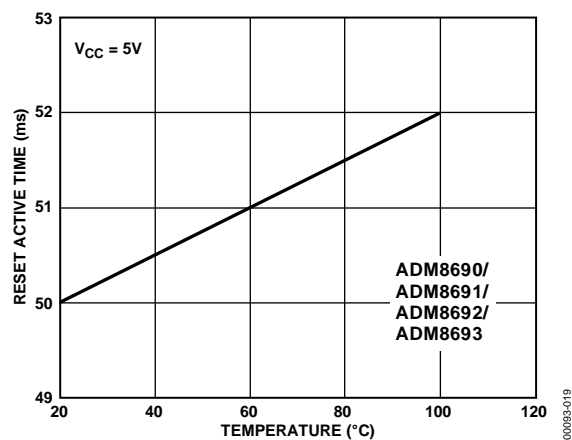


Figure 9. Reset Active Time vs. Temperature

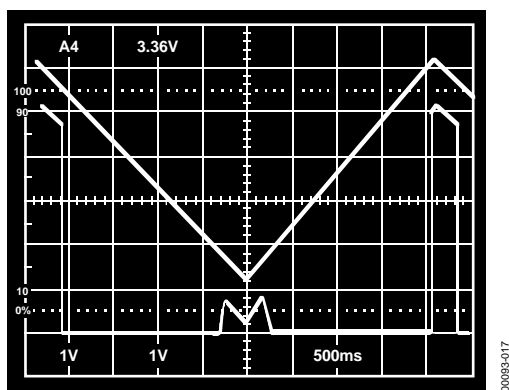


Figure 7. Reset Output Voltage vs. Supply Voltage

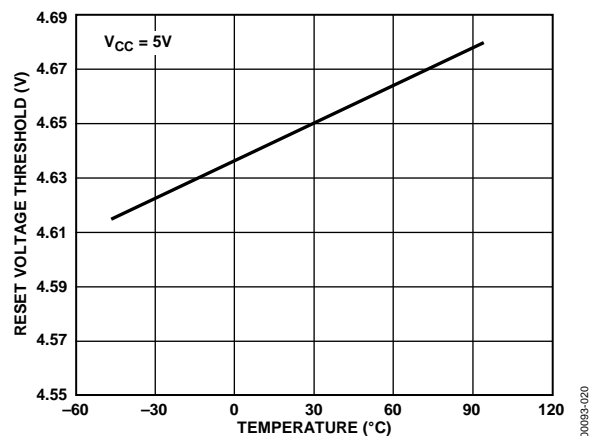


Figure 10. Reset Voltage Threshold vs. Temperature

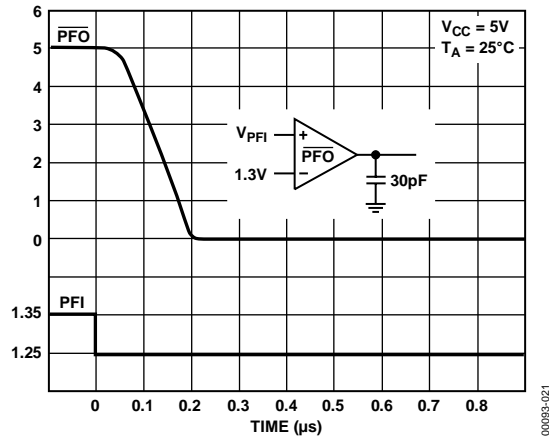


Figure 11. Power-Fail Comparator Response Time Falling

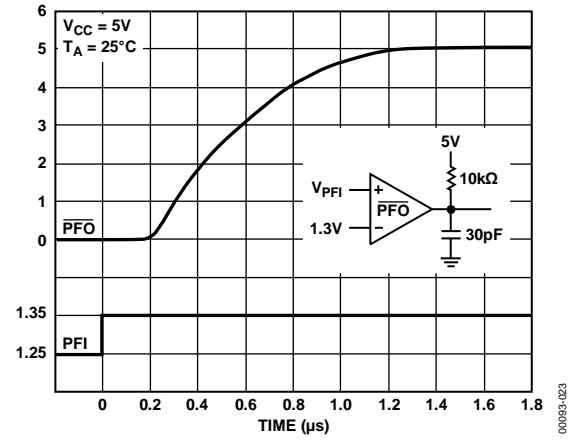


Figure 13. Power-Fail Comparator Response Time with Pull-Up Resistor

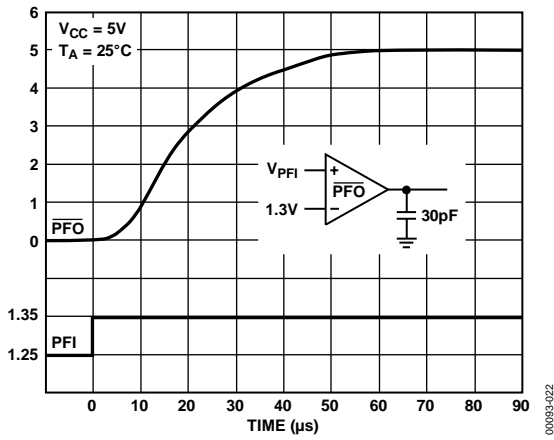


Figure 12. Power-Fail Comparator Response Time Rising

## CIRCUIT INFORMATION

### BATTERY SWITCHOVER SECTION

The battery switchover circuit compares  $V_{CC}$  to the  $V_{BATT}$  input, and connects  $V_{OUT}$  to whichever is higher. Switchover occurs when  $V_{CC}$  is 50 mV higher than  $V_{BATT}$  as  $V_{CC}$  falls, and when  $V_{CC}$  is 70 mV greater than  $V_{BATT}$  as  $V_{CC}$  rises. This 20 mV of hysteresis prevents repeated rapid switching if  $V_{CC}$  falls very slowly or remains nearly equal to the battery voltage.

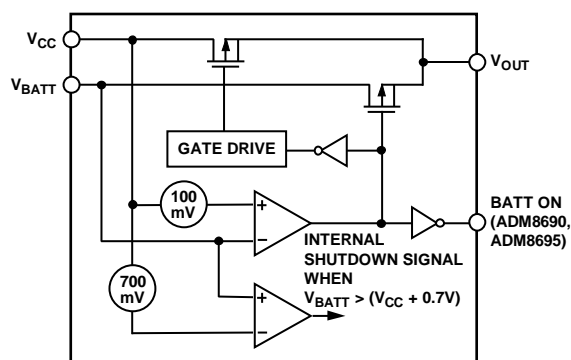


Figure 14. Battery Switchover Schematic

During normal operation, with  $V_{CC}$  higher than  $V_{BATT}$ ,  $V_{CC}$  is internally switched to  $V_{OUT}$  through an internal PMOS transistor switch. This switch has a typical on resistance of  $0.7\ \Omega$  and can supply up to 100 mA at the  $V_{OUT}$  terminal.  $V_{OUT}$  is normally used to drive a RAM memory bank, requiring instantaneous currents of greater than 100 mA. If this is the case, a bypass capacitor should be connected to  $V_{OUT}$ . The capacitor provides the peak current transients to the RAM. A capacitance value of  $0.1\ \mu\text{F}$  or greater can be used.

If the continuous output current requirement at  $V_{OUT}$  exceeds 100 mA, or if a lower  $V_{CC} - V_{OUT}$  voltage differential is desired, an external PNP pass transistor can be connected in parallel with the internal transistor. The BATT ON output (ADM8691/ADM8693/ADM8695) can directly drive the base of the external transistor.

A  $7\ \Omega$  MOSFET switch connects the  $V_{BATT}$  input to  $V_{OUT}$  during battery backup. This MOSFET has very low input-to-output differential (dropout voltage) at the low current levels required for battery back up of CMOS RAM or other low power CMOS circuitry. The supply current in battery back up is typically  $0.4\ \mu\text{A}$ .

The ADM8690/ADM8691/ADM8695 operate with battery voltages from 2.0 V to 4.25 V, and the ADM8692/ADM8693 operate with battery voltages from 2.0 V to 4.0 V. High value capacitors, either standard electrolytic or the farad-size, double-layer capacitors, can also be used for short-term memory backup. A small charging current of typically 10 nA ( $0.1\ \mu\text{A}$  maximum) flows out of the  $V_{BATT}$  terminal. This current is useful for maintaining rechargeable batteries in a fully

charged condition. This extends the life of the backup battery by compensating for its self-discharge current. Also note that this current poses no problem when lithium batteries are used for backup because the maximum charging current ( $0.1\ \mu\text{A}$ ) is safe for even the smallest lithium cells.

If the battery switchover section is not used,  $V_{BATT}$  should be connected to GND and  $V_{OUT}$  should be connected to  $V_{CC}$ .

### POWER-FAIL RESET OUTPUT

$\overline{\text{RESET}}$  is an active low output that provides a  $\overline{\text{RESET}}$  signal to the microprocessor whenever  $V_{CC}$  is at an invalid level. When  $V_{CC}$  falls below the reset threshold, the  $\overline{\text{RESET}}$  output is forced low. The nominal reset voltage threshold is 4.65 V (ADM8690/ADM8691/ADM8695) or 4.4 V (ADM8692/ADM8693).

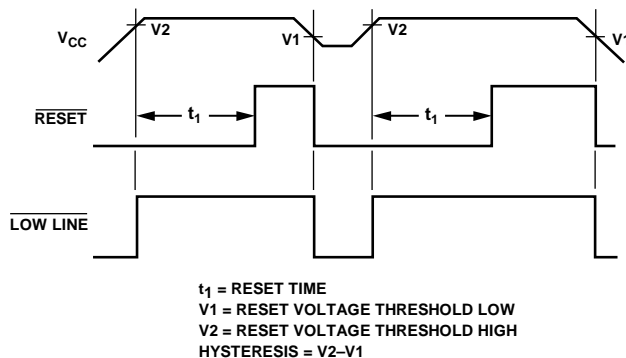


Figure 15. Power-Fail Reset Timing

On power-up,  $\overline{\text{RESET}}$  remains low for 50 ms (200 ms for ADM8695) after  $V_{CC}$  rises above the appropriate reset threshold. This allows time for the power supply and microprocessor to stabilize. On power-down, the  $\overline{\text{RESET}}$  output remains low with  $V_{CC}$  as low as 1 V. This ensures that the microprocessor is held in a stable shutdown condition.

This  $\overline{\text{RESET}}$  active time is adjustable on the ADM8691/ADM8693/ADM8695 by using an external oscillator or by connecting an external capacitor to the OSC IN pin. Refer to Table 5 and Figure 17, Figure 18, Figure 19, and Figure 20.

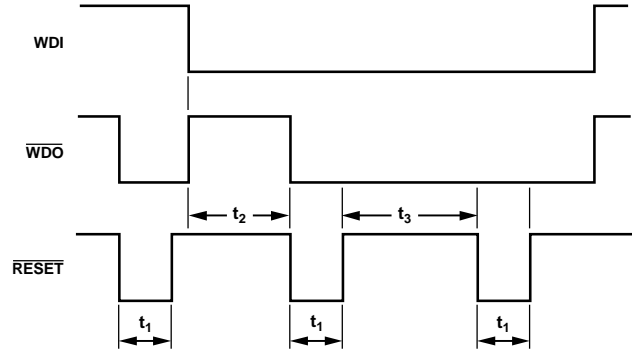
The guaranteed minimum and maximum thresholds of the ADM8690/ADM8691/ADM8695 are 4.5 V and 4.73 V, and the guaranteed thresholds of the ADM8692/ADM8693 are 4.25 V and 4.48 V. The ADM8690/ADM8691/ADM8695 are, therefore, compatible with 5 V supplies with a +10%, -5% tolerance and the ADM8692/ADM8693 are compatible with  $5\ \text{V} \pm 10\%$  supplies. The reset threshold comparator has approximately 50 mV of hysteresis. The response time of the reset voltage comparator is less than  $1\ \mu\text{s}$ . If glitches are present on the  $V_{CC}$  line that could cause spurious reset pulses,  $V_{CC}$  should be decoupled close to the device.

In addition to  $\overline{\text{RESET}}$ , the ADM8691/ADM8693/ADM8695 contain an active high RESET output. This is the complement of  $\overline{\text{RESET}}$  and is intended for processors requiring an active high reset signal.

## WATCHDOG TIMER RESET

The watchdog timer circuit monitors the activity of the micro-processor to check that it is not stalled in an indefinite loop. An output line on the processor is used to toggle the watchdog input (WDI) line. If this line is not toggled within the selected timeout period, a RESET pulse is generated. The nominal watchdog timeout period is preset at 1.6 seconds on the ADM8690 and ADM8692. The ADM8691/ADM8693/ADM8695 can be configured for either a fixed short 100 ms, or a long 1.6 second timeout period, or for an adjustable timeout period. If the short period is selected, some systems are unable to service the watchdog timer immediately after a reset, so the ADM8691/ADM8693/ADM8695 automatically select the long timeout period directly after a reset is issued. The watchdog timer is restarted at the end of reset, whether the reset was caused by lack of activity on WDI or by  $V_{CC}$  falling below the reset threshold.

The normal (short) timeout period becomes effective following the first transition of WDI after  $\overline{\text{RESET}}$  has gone inactive. The watchdog timeout period restarts with each transition on the WDI pin. To ensure that the watchdog timer does not time out, either a high-to-low or low-to-high transition on the WDI pin must occur at, or less than, the minimum timeout period. If WDI remains permanently either high or low, reset pulses are issued after each long (1.6 s) timeout period. The watchdog monitor can be deactivated by floating the watchdog input (WDI) or by connecting it to midsupply.



$t_1$  = RESET TIME  
 $t_2$  = NORMAL (SHORT) WATCHDOG TIMEOUT PERIOD  
 $t_3$  = WATCHDOG TIMEOUT PERIOD IMMEDIATELY FOLLOWING A RESET

200-63000

Figure 16. Watchdog Timeout Period and Reset Active Time

Table 5. ADM8691, ADM8693, ADM8695 Reset Pulse Width and Watchdog Timeout Selections

| OSC SEL          | OSC IN               | Watchdog Timeout Period                 |  | Reset Active Period                     |   |
|------------------|----------------------|---|--|---|---|
|                  |                      | Normal                                  | Immediately After Reset                | ADM8691/ADM8693                         | ADM8695                                 |
| Low <sup>1</sup> | External clock input | 1024 CLKs                               | 4096 CLKs                              | 512 CLKs                                | 2048 CLKs                               |
| Low <sup>1</sup> | External capacitor   | $400 \text{ ms} \times C/47 \text{ pF}$ | $1.6 \text{ s} \times C/47 \text{ pF}$ | $200 \text{ ms} \times C/47 \text{ pF}$ | $520 \text{ ms} \times C/47 \text{ pF}$ |
| Floating or high | Low                  | 100 ms                                  | 1.6 s                                  | 50 ms                                   | 200 ms                                  |
| Floating or high | Floating or high     | 1.6 s                                   | 1.6 s                                  | 50 ms                                   | 200 ms                                  |

<sup>1</sup> With the OSC SEL pin low, OSC IN can be driven by an external clock signal, or an external capacitor (C) can be connected between OSC IN and GND. The nominal internal oscillator frequency is 10.24 kHz. The nominal oscillator frequency with external capacitor is:  $F_{\text{OSC}} (\text{Hz}) = 184,000/C (\text{pF})$ .

# ADM8690/ADM8691/ADM8692/ADM8693/ADM8695

On the ADM8690/ADM8692 the watchdog timeout period is fixed at 1.6 seconds and the reset pulse width is fixed at 50 ms. The ADM8691/ADM8693/ADM8695 allow these times to be adjusted, as shown in Table 5. Figure 17, Figure 18, Figure 19, and Figure 20 show the various oscillator configurations that can be used to adjust the reset pulse width and watchdog timeout period.

The internal oscillator is enabled when OSC SEL is high or floating. In this mode, OSC IN selects between the 1.6 second and 100 ms watchdog timeout periods. With OSC IN connected high or floating, the 1.6 second timeout period is selected; and with it connected low, the 100 ms timeout period is selected. In either case, the timeout period is 1.6 seconds immediately after a reset. This gives the microprocessor time to reinitialize the system. If OSC IN is low, the 100 ms watchdog period becomes effective after the first transition of WDI. The software should be written such that the input/output port driving WDI is left in its power-up reset state until the initialization routines are completed and the microprocessor is able to toggle WDI at the minimum watchdog timeout period of 70 ms.

## WATCHDOG OUTPUT (WDO)

The Watchdog Output  $\overline{\text{WDO}}$  (ADM8691/ADM8693/ADM8695) provides a status output that goes low if the watchdog timer times out and remains low until set high by the next transition on the watchdog input. WDO is also set high when  $V_{CC}$  goes below the reset threshold.

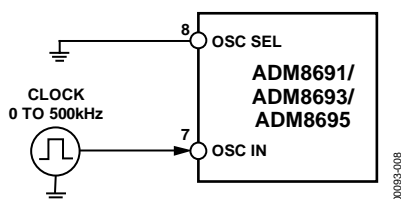


Figure 17. External Clock Source

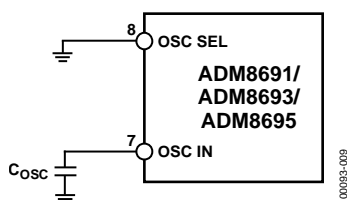


Figure 18. External Capacitor

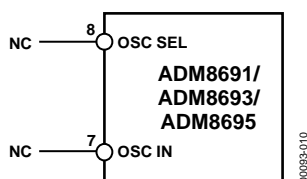


Figure 19. Internal Oscillator (1.6 Second Watchdog)

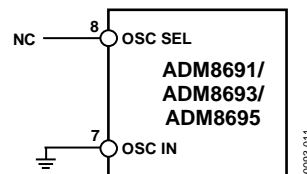


Figure 20. Internal Oscillator (100 ms Watchdog)

## CE GATING AND RAM WRITE PROTECTION (ADM8691/ADM8693/ADM8695)

The ADM8691/ADM8693/ADM8695 products include memory protection circuitry that ensures the integrity of data in memory by preventing write operations when  $V_{CC}$  is at an invalid level. There are two additional pins ( $\overline{\text{CE}}_{\text{IN}}$  and  $\overline{\text{CE}}_{\text{OUT}}$ ) that can be used to control the chip enable or write inputs of CMOS RAM. When  $V_{CC}$  is present,  $\overline{\text{CE}}_{\text{OUT}}$  is a buffered replica of  $\overline{\text{CE}}_{\text{IN}}$ , with a 3 ns propagation delay. When  $V_{CC}$  falls below the reset voltage threshold or  $V_{\text{BATT}}$ , an internal gate forces  $\overline{\text{CE}}_{\text{OUT}}$  high, independent of  $\overline{\text{CE}}_{\text{IN}}$ .

$\overline{\text{CE}}_{\text{OUT}}$  typically drives the  $\overline{\text{CE}}$ ,  $\overline{\text{CS}}$ , or write input of battery backed up CMOS RAM. This ensures the integrity of the data in memory by preventing write operations when  $V_{CC}$  is at an invalid level. Similar protection of EEPROMs can be achieved using the  $\overline{\text{CE}}_{\text{OUT}}$  to drive the store or write inputs.

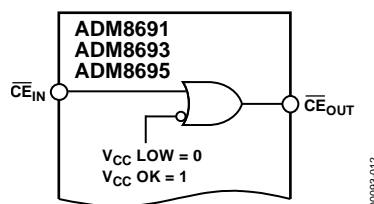
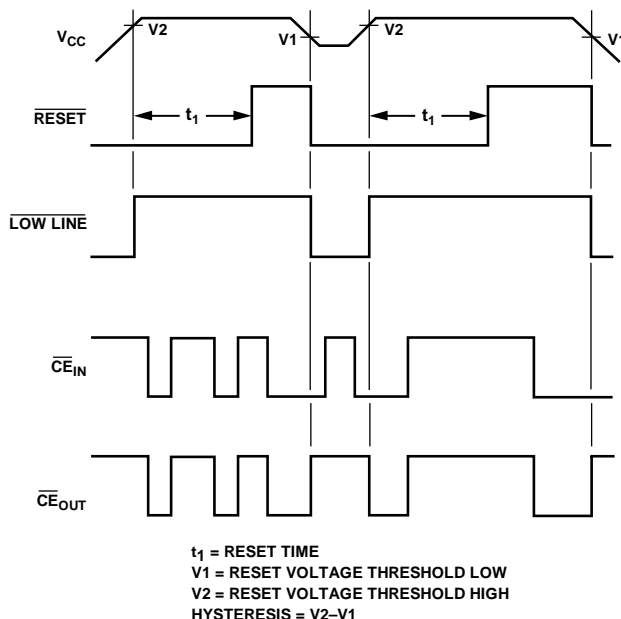


Figure 21. Chip Enable Gating



$t_1$  = RESET TIME  
 $V_1$  = RESET VOLTAGE THRESHOLD LOW  
 $V_2$  = RESET VOLTAGE THRESHOLD HIGH  
 HYSTERESIS =  $V_2 - V_1$

Figure 22. Chip Enable Timing

## POWER-FAIL WARNING COMPARATOR

An additional comparator is provided for early warning of failure in the microprocessor power supply. The power-fail input (PFI) is compared to an internal 1.3 V reference. The power-fail output (PFO) goes low when the voltage at PFI is less than 1.3 V. Typically, PFI is driven by an external voltage divider that senses either the unregulated dc input to the system 5 V regulator or the regulated 5 V output. The voltage divider ratio can be chosen such that the voltage at PFI falls below 1.3 V several milliseconds before the 5 V power supply falls below the reset threshold.  $\overline{\text{PFO}}$  is normally used to interrupt the microprocessor so that data can be stored in RAM and the shut-down procedure executed before power is lost.

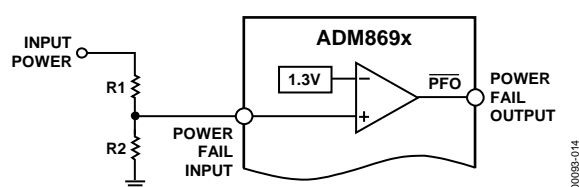


Figure 23. Power-Fail Comparator

Table 6. Input and Output Status in Battery Backup Mode

| Signal                              | Status  |
|-------------------------------------|---|
| $V_{\text{OUT}}$                    | $V_{\text{OUT}}$ is connected to $V_{\text{BATT}}$ via an internal PMOS switch.   |
| $\overline{\text{RESET}}$           | Logic low.  |
| RESET                               | Logic high. The open-circuit output voltage is equal to $V_{\text{OUT}}$ .  |
| $\overline{\text{LOW LINE}}$        | Logic low.  |
| BATT ON                             | Logic high. The open-circuit voltage is equal to $V_{\text{OUT}}$ .   |
| WDI                                 | WDI is ignored. It is internally disconnected from the internal pull-up resistor and does not source or sink current as long as its input voltage is between GND and $V_{\text{OUT}}$ . The input voltage does not affect supply current.                       |
| $\overline{\text{WDO}}$             | Logic high. The open circuit voltage is equal to $V_{\text{OUT}}$ .   |
| PFI                                 | The power-fail comparator is turned off and has no effect on the power-fail output.   |
| $\overline{\text{PFO}}$             | Logic low.  |
| $\overline{\text{CE}}_{\text{IN}}$  | $\overline{\text{CE}}_{\text{IN}}$ is ignored. It is internally disconnected from its internal pull-up and does not source or sink current as long as its input voltage is between GND and $V_{\text{OUT}}$ . The input voltage does not affect supply current. |
| $\overline{\text{CE}}_{\text{OUT}}$ | Logic high. The open circuit voltage is equal to $V_{\text{OUT}}$ .   |
| OSC IN                              | OSC IN is ignored.  |
| OSC SEL                             | OSC SEL is ignored.   |

## APPLICATION INFORMATION

### INCREASING THE DRIVE CURRENT

If the continuous output current requirements at  $V_{OUT}$  exceed 100 mA, or if a lower  $V_{CC} - V_{OUT}$  voltage differential is desired, an external PNP pass transistor can be connected in parallel with the internal transistor. The BATT ON output (ADM8691/ADM8693/ADM8695) can directly drive the base of the external transistor.

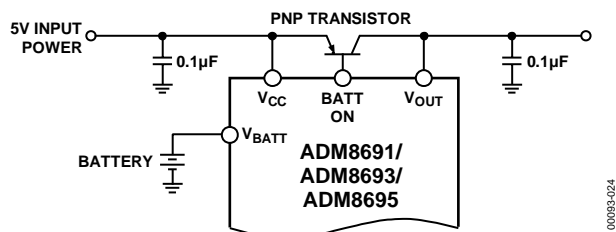


Figure 24. Increasing the Drive Current

### USING A RECHARGEABLE BATTERY FOR BACKUP

If a capacitor or a rechargeable battery is used for backup then the charging resistor should be connected to  $V_{OUT}$  because this eliminates the discharge path that would exist during power-down if the resistor is connected to  $V_{CC}$ .

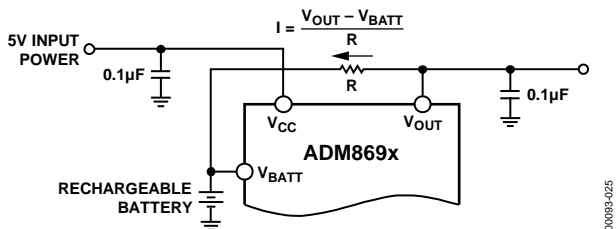


Figure 25. Rechargeable Battery

### ADDING HYSTERESIS TO THE POWER-FAIL COMPARATOR

For increased noise immunity, hysteresis can be added to the power-fail comparator. Because the comparator circuit is noninverting, hysteresis can be added simply by connecting a resistor between the  $\overline{PFO}$  output and the PFI input as shown in Figure 26. When  $\overline{PFO}$  is low, Resistor  $R_3$  sinks current from the summing junction at the PFI pin. When  $\overline{PFO}$  is high, the series combination of  $R_3$  and  $R_4$  sources current into the PFI summing junction. This results in differing trip levels for the comparator.

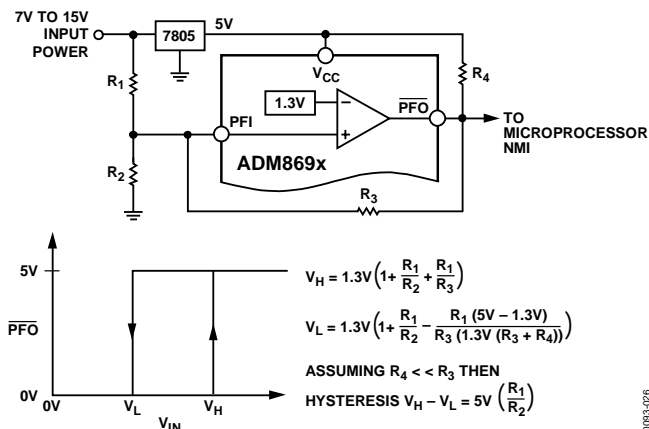


Figure 26. Adding Hysteresis to the Power-Fail Comparator

### MONITORING THE STATUS OF THE BATTERY

The power-fail comparator can be used to monitor the status of the backup battery instead of the power supply, if desired. This is shown in Figure 27. The PFI input samples the battery voltage and generates an active low  $\overline{PFO}$  signal when the battery voltage drops below a chosen threshold. It can be necessary to apply a test load to determine the loaded battery voltage. This is done under processor control using  $\overline{CE}_{OUT}$ . Because  $\overline{CE}_{OUT}$  is forced high during the battery backup mode, the test load is not applied to the battery while it is in use, even if the microprocessor is not powered.

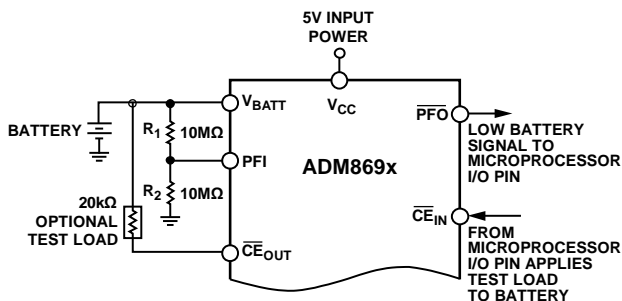


Figure 27. Monitoring the Battery Status

## ALTERNATE WATCHDOG INPUT DRIVE CIRCUITS

The watchdog feature can be enabled and disabled under program control by driving WDI with a three-state buffer (see Figure 28). When three-stated, the WDI input floats, thereby disabling the watchdog timer.

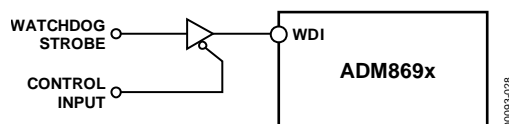


Figure 28. Programming the Watchdog Input

This circuit is not entirely foolproof, and it is possible for a software fault to erroneously three-state the buffer preventing the ADM869x from detecting that the microprocessor is no longer operating correctly. In most cases, a better method is to extend the watchdog period rather than disable the watchdog.

This can be done under program control using the circuit shown in Figure 29. When the control input is high, the OSC SEL pin is low and the watchdog timeout is set by the external capacitor. A 0.01  $\mu\text{F}$  capacitor sets a watchdog time-out delay of 100 seconds. When the control input is low, the OSC SEL pin is driven high, selecting the internal oscillator. The 100 ms or the 1.6 s period is chosen, depending on which diode is used, as shown in Figure 29. With D1 inserted, the internal timeout is set at 100 ms; with D2 inserted, the timeout is set at 1.6 seconds.

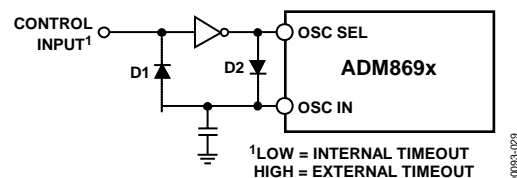


Figure 29. Programming the Watchdog Input

## TYPICAL APPLICATIONS

### ADM8690 AND ADM8692

Figure 30 shows the ADM8690/ADM8692 in a typical power monitoring, battery backup application.  $V_{OUT}$  powers the CMOS RAM. Under normal operating conditions with  $V_{CC}$  present,  $V_{OUT}$  is internally connected to  $V_{CC}$ . If a power failure occurs,  $V_{CC}$  decays and  $V_{OUT}$  is switched to  $V_{BATT}$ , thereby maintaining power for the CMOS RAM. A RESET pulse is also generated when  $V_{CC}$  falls below 4.65 V for the ADM8690 or 4.4 V for the ADM8692. RESET remains low for 50 ms after  $V_{CC}$  returns to 5 V.

The watchdog timer input (WDI) monitors an input/output line from the microprocessor system. This line must be toggled once every 1.6 seconds to verify correct software execution. Failure to toggle the line indicates that the microprocessor system is not correctly executing its program and can be tied up in an endless loop. If this happens, a reset pulse is generated to initialize the microprocessor.

If the watchdog timer is not needed, the WDI input should be left floating.

The power-fail input, PFI, monitors the input power supply via a resistive divider network. The voltage on the PFI input is compared with a precision 1.3 V internal reference. If the input voltage drops below 1.3 V, a power-fail output (PFO) signal is generated. This warns of an impending power failure and can be used to interrupt the processor so that the system can be shut down in an orderly fashion. The resistors in the sensing network are ratioed to give the desired power-fail threshold voltage ( $V_T$ ).

$$V_T = (1.3 R1/R2) + 1.3 \text{ V}$$

$$R1/R2 = (V_T/1.3) - 1$$

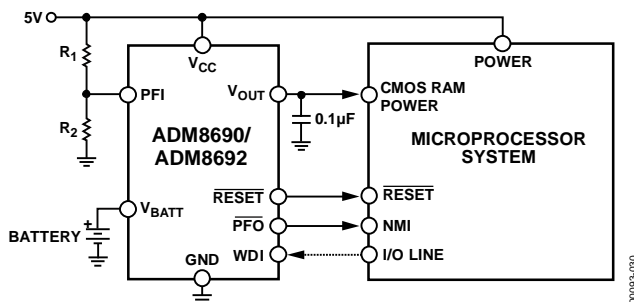


Figure 30. ADM8690/ADM8692 Typical Application Circuit A

Figure 31 shows a similar application, but in this case the PFI input monitors the unregulated input to the 7805 voltage regulator. This gives an earlier warning of an impending power failure. It is useful with processors operating at low speeds or where there are a significant number of housekeeping tasks to be completed before the power is lost.

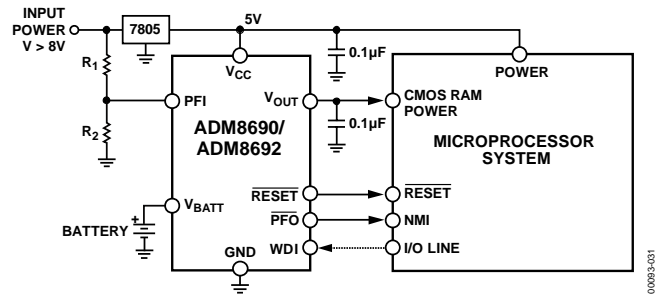


Figure 31. ADM8690/ADM8692 Typical Application Circuit B

### ADM8691, ADM8693, AND ADM8695

A typical connection for the ADM8691/ADM8693/ADM8695 is shown in Figure 32. CMOS RAM is powered from  $V_{OUT}$ . When 5 V power is present, this is routed to  $V_{OUT}$ . If  $V_{CC}$  fails,  $V_{BATT}$  is routed to  $V_{OUT}$ .  $V_{OUT}$  can supply up to 100 mA from  $V_{CC}$ , but if more current is required, an external PNP transistor can be added. When  $V_{CC}$  is higher than  $V_{BATT}$ , the BATT ON output goes low, providing up to 25 mA of base drive for the external transistor. A 0.1  $\mu$ F capacitor is connected to  $V_{OUT}$  to supply the transient currents for CMOS RAM. When  $V_{CC}$  is lower than  $V_{BATT}$ , an internal 20  $\Omega$  MOSFET connects the backup battery to  $V_{OUT}$ .

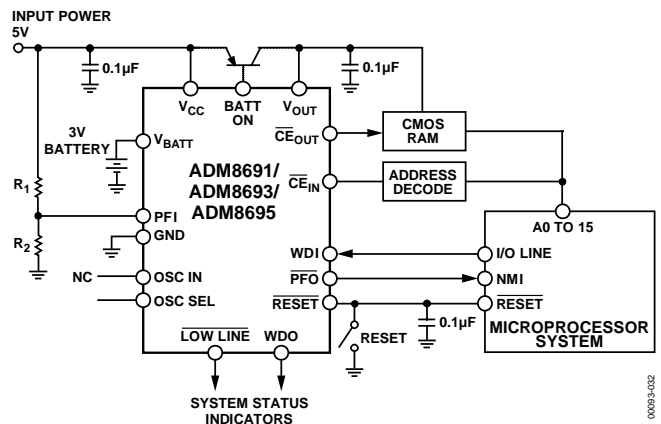


Figure 32. ADM8691/ADM8693/ADM8695 Typical Application

### RESET OUTPUT

The internal voltage detector monitors  $V_{CC}$  and generates a RESET output to hold the microprocessor reset line low when  $V_{CC}$  is below 4.65 V (4.4 V for ADM8693). An internal timer holds RESET low for 50 ms (200 ms for the ADM8695) after  $V_{CC}$  rises above 4.65 V (4.4 V for the ADM8693). This prevents repeated toggling of RESET, even if the 5 V power drops out and recovers with each power line cycle.

The crystal oscillator normally used to generate the clock for microprocessors can take several milliseconds to stabilize. Because most microprocessors need several clock cycles to reset, RESET must be held low until the microprocessor clock oscillator has started. The power-up RESET pulse lasts 50 ms

(200 ms for the ADM8695) to allow for this oscillator start-up time. If a different reset pulse width is required, a capacitor should be connected to OSC IN, or an external clock can be used. Refer to Table 5 and Figure 17, Figure 18, Figure 19, and Figure 20. The manual reset switch and the 0.1  $\mu$ F capacitor connected to the reset line can be omitted if a manual reset is not needed. An inverted, active high, RESET output is also available.

## POWER-FAIL DETECTOR

The 5 V  $V_{CC}$  power line is monitored via a resistive potential divider connected to the power-fail input (PFI). When the voltage at PFI falls below 1.3 V, the power-fail output ( $\overline{PFO}$ ) drives the processor's NMI input low. If, for example, a power-fail threshold of 4.8 V is set with Resistor  $R_1$  and Resistor  $R_2$ , the microprocessor has the time when  $V_{CC}$  falls from 4.8 V to 4.65 V to save data into RAM. An earlier power-fail warning can be generated if the unregulated dc input to the 5 V regulator is available for monitoring. This allows more time for microprocessor housekeeping tasks to be completed before power is lost.

## RAM WRITE PROTECTION

The ADM8691/ADM8693/ADM8695  $\overline{CE}_{OUT}$  line drives the chip select inputs of the CMOS RAM.  $\overline{CE}_{OUT}$  follows  $\overline{CE}_{IN}$  as long as  $V_{CC}$  is above the 4.65 V (4.4 V for the ADM8693) reset threshold.

If  $V_{CC}$  falls below the reset threshold,  $\overline{CE}_{OUT}$  goes high, independent of the logic level at  $\overline{CE}_{IN}$ . This prevents the

microprocessor from writing erroneous data into RAM during power-up, power-down, brownouts, and momentary power interruptions.

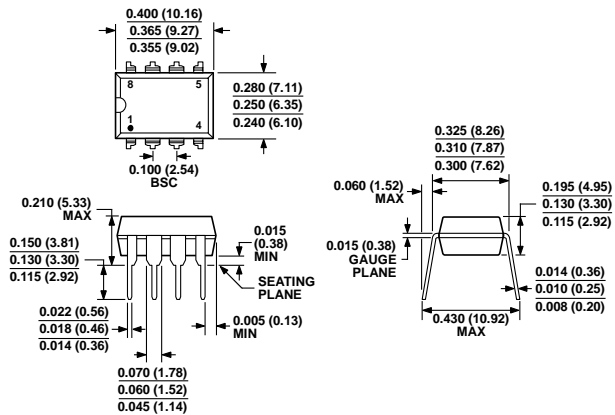
## WATCHDOG TIMER

The microprocessor drives the watchdog input (WDI) with an input/output line. When OSC IN and OSC SEL are unconnected, the microprocessor must toggle the WDI pin once every 1.6 seconds to verify proper software execution. If a hardware or software failure occurs such that WDI is not toggled, the ADM8691/ADM8693 issues a 50 ms (200 ms for the ADM8695) RESET pulse after 1.6 seconds. This typically restarts the microprocessor power-up routine. A new RESET pulse is issued every 1.6 seconds until WDI is again strobed. If a different watchdog timeout period is required, a capacitor should be connected to OSC IN or an external clock can be used. Refer to Table 5 and Figure 17, Figure 18, Figure 19, and Figure 20.

The watchdog output ( $\overline{WDO}$ ) goes low if the watchdog timer is not serviced within its timeout period. Once  $\overline{WDO}$  goes low, it remains low until a transition occurs at WDI. The watchdog timer feature can be disabled by leaving WDI unconnected.

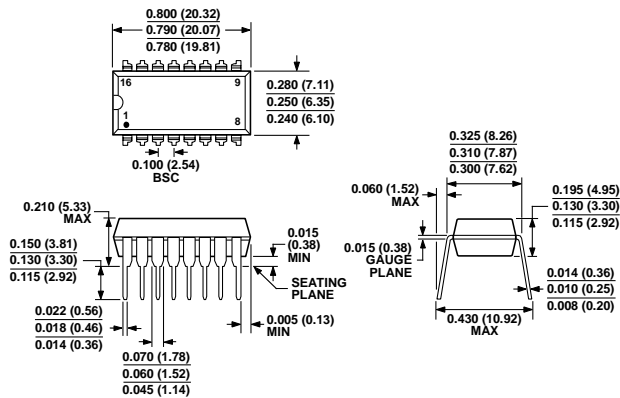
The RESET output has an internal 3  $\mu$ A pull-up and can either connect to an open collector reset bus or directly drive a CMOS gate without an external pull-up resistor.

## OUTLINE DIMENSIONS



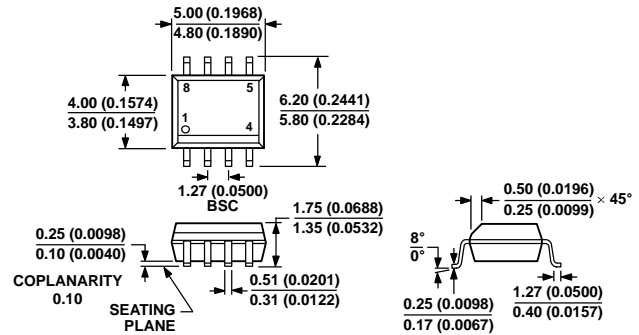
COMPLIANT TO JEDEC STANDARDS MS-001  
CONTROLLING DIMENSIONS ARE IN INCHES; MILLIMETER DIMENSIONS (IN PARENTHESES) ARE ROUNDED-OFF INCH EQUIVALENTS FOR REFERENCE ONLY AND ARE NOT APPROPRIATE FOR USE IN DESIGN. CORNER LEADS MAY BE CONFIGURED AS WHOLE OR HALF LEADS.

Figure 33. 8-Lead Plastic Dual In-Line Package [PDIP] (N-8)  
Dimensions shown in inches and (millimeters)



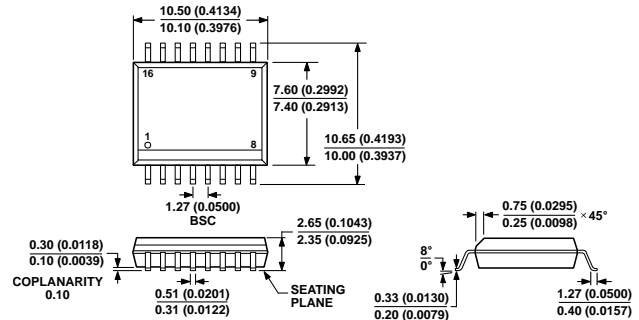
COMPLIANT TO JEDEC STANDARDS MS-001-AB  
CONTROLLING DIMENSIONS ARE IN INCHES; MILLIMETER DIMENSIONS (IN PARENTHESES) ARE ROUNDED-OFF INCH EQUIVALENTS FOR REFERENCE ONLY AND ARE NOT APPROPRIATE FOR USE IN DESIGN. CORNER LEADS MAY BE CONFIGURED AS WHOLE OR HALF LEADS.

Figure 34. 16-Lead Plastic Dual In-Line Package [PDIP] (N-16)  
Dimensions shown in inches and (millimeters)



COMPLIANT TO JEDEC STANDARDS MS-012-AA  
CONTROLLING DIMENSIONS ARE IN MILLIMETERS; INCH DIMENSIONS (IN PARENTHESES) ARE ROUNDED-OFF MILLIMETER EQUIVALENTS FOR REFERENCE ONLY AND ARE NOT APPROPRIATE FOR USE IN DESIGN.

Figure 35. 8-Lead Standard Small Outline Package [SOIC\_N] Narrow Body (R-8)  
Dimensions shown in millimeters and (inches)



COMPLIANT TO JEDEC STANDARDS MS-013-AA  
CONTROLLING DIMENSIONS ARE IN MILLIMETERS; INCH DIMENSIONS (IN PARENTHESES) ARE ROUNDED-OFF MILLIMETER EQUIVALENTS FOR REFERENCE ONLY AND ARE NOT APPROPRIATE FOR USE IN DESIGN.

Figure 36. 16-Lead Standard Small Outline Package [SOIC\_W] Wide Body (RW-16)  
Dimensions shown in millimeters and (inches)

# ADM8690/ADM8691/ADM8692/ADM8693/ADM8695

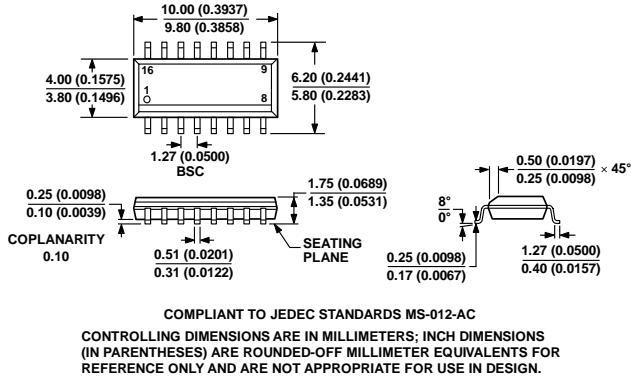


Figure 37. 16-Lead Standard Small Outline Package [SOIC\_N]  
Narrow Body  
(R-16)  
Dimensions shown in millimeters and (inches)

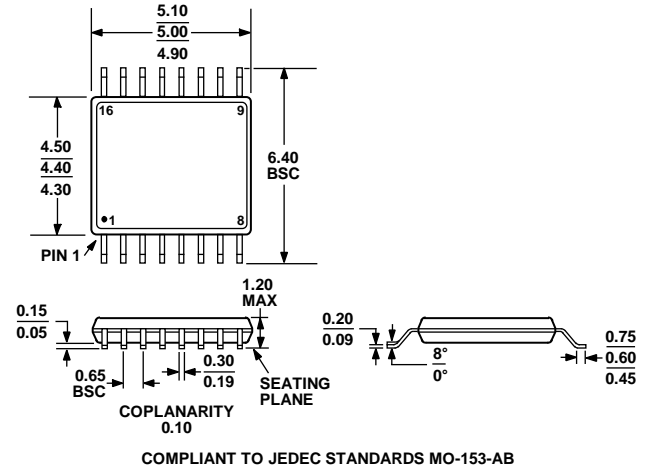


Figure 38. 16-Lead Thin Shrink Small Outline Package [TSSOP]  
(RU-16)  
Dimensions shown in millimeters

## ORDERING GUIDE

| Model <sup>1</sup> | Temperature Range | Package Description                               | Package Option |
|--------------------|-------------------|---|----------------|
| ADM8690AN          | −40°C to +85°C    | 8-Lead Plastic Dual In-Line Package [PDIP]        | N-8            |
| ADM8690ANZ         | −40°C to +85°C    | 8-Lead Plastic Dual In-Line Package [PDIP]        | N-8            |
| ADM8690ARN         | −40°C to +85°C    | 8-Lead Standard Small Outline Package [SOIC_N]    | R-8            |
| ADM8690ARN-REEL    | −40°C to +85°C    | 8-Lead Standard Small Outline Package [SOIC_N]    | R-8            |
| ADM8690ARNZ        | −40°C to +85°C    | 8-Lead Standard Small Outline Package [SOIC_N]    | R-8            |
| ADM8691ANZ         | −40°C to +85°C    | 16-Lead Plastic Dual In-Line Package [PDIP]       | N-16           |
| ADM8691ARN         | −40°C to +85°C    | 16-Lead Standard Small Outline Package [SOIC_N]   | R-16           |
| ADM8691ARN-REEL    | −40°C to +85°C    | 16-Lead Standard Small Outline Package [SOIC_N]   | R-16           |
| ADM8691ARNZ        | −40°C to +85°C    | 16-Lead Standard Small Outline Package [SOIC_N]   | R-16           |
| ADM8691ARW         | −40°C to +85°C    | 16-Lead Standard Small Outline Package [SOIC_W]   | RW-16          |
| ADM8691ARW-REEL    | −40°C to +85°C    | 16-Lead Standard Small Outline Package [SOIC_W]   | RW-16          |
| ADM8691ARWZ        | −40°C to +85°C    | 16-Lead Standard Small Outline Package [SOIC_W]   | RW-16          |
| ADM8691ARU         | −40°C to +85°C    | 16-Lead Thin Shrink Small Outline Package [TSSOP] | RU-16          |
| ADM8691ARU-REEL    | −40°C to +85°C    | 16-Lead Thin Shrink Small Outline Package [TSSOP] | RU-16          |
| ADM8691ARUZ        | −40°C to +85°C    | 16-Lead Thin Shrink Small Outline Package [TSSOP] | RU-16          |
| ADM8692ARNZ        | −40°C to +85°C    | 8-Lead Standard Small Outline Package [SOIC_N]    | R-8            |
| ADM8693AN          | −40°C to +85°C    | 16-Lead Plastic Dual In-Line Package [PDIP]       | N-16           |
| ADM8693ANZ         | −40°C to +85°C    | 16-Lead Plastic Dual In-Line Package [PDIP]       | N-16           |
| ADM8693ARN         | −40°C to +85°C    | 16-Lead Standard Small Outline Package [SOIC_N]   | R-16           |
| ADM8693ARN-REEL    | −40°C to +85°C    | 16-Lead Standard Small Outline Package [SOIC_N]   | R-16           |
| ADM8693ARNZ        | −40°C to +85°C    | 16-Lead Standard Small Outline Package [SOIC_N]   | R-16           |
| ADM8693ARW         | −40°C to +85°C    | 16-Lead Standard Small Outline Package [SOIC_W]   | RW-16          |
| ADM8693ARW-REEL    | −40°C to +85°C    | 16-Lead Standard Small Outline Package [SOIC_W]   | RW-16          |
| ADM8693ARWZ        | −40°C to +85°C    | 16-Lead Standard Small Outline Package [SOIC_W]   | RW-16          |
| ADM8693ARU-REEL    | −40°C to +85°C    | 16-Lead Thin Shrink Small Outline Package [TSSOP] | RU-16          |
| ADM8693ARUZ        | −40°C to +85°C    | 16-Lead Thin Shrink Small Outline Package [TSSOP] | RU-16          |
| ADM8695ARW         | −40°C to +85°C    | 16-Lead Standard Small Outline Package [SOIC_W]   | RW-16          |
| ADM8695ARW-REEL    | −40°C to +85°C    | 16-Lead Standard Small Outline Package [SOIC_W]   | RW-16          |
| ADM8695ARWZ        | −40°C to +85°C    | 16-Lead Standard Small Outline Package [SOIC_W]   | RW-16          |

<sup>1</sup> Z = RoHS Compliant Part.

## **NOTES**

Компания «Океан Электроники» предлагает заключение долгосрочных отношений при поставках импортных электронных компонентов на взаимовыгодных условиях!

Наши преимущества:

- Поставка оригинальных импортных электронных компонентов напрямую с производств Америки, Европы и Азии, а так же с крупнейших складов мира;
- Широкая линейка поставок активных и пассивных импортных электронных компонентов (более 30 млн. наименований);
- Поставка сложных, дефицитных, либо снятых с производства позиций;
- Оперативные сроки поставки под заказ (от 5 рабочих дней);
- Экспресс доставка в любую точку России;
- Помощь Конструкторского Отдела и консультации квалифицированных инженеров;
- Техническая поддержка проекта, помощь в подборе аналогов, поставка прототипов;
- Поставка электронных компонентов под контролем ВП;
- Система менеджмента качества сертифицирована по Международному стандарту ISO 9001;
- При необходимости вся продукция военного и аэрокосмического назначения проходит испытания и сертификацию в лаборатории (по согласованию с заказчиком);
- Поставка специализированных компонентов военного и аэрокосмического уровня качества (Xilinx, Altera, Analog Devices, Intersil, Interpoint, Microsemi, Actel, Aeroflex, Peregrine, VPT, Syfer, Eurofarad, Texas Instruments, MS Kennedy, Miteq, Cobham, E2V, MA-COM, Hittite, Mini-Circuits, General Dynamics и др.);

Компания «Океан Электроники» является официальным дистрибьютором и эксклюзивным представителем в России одного из крупнейших производителей разъемов военного и аэрокосмического назначения «JONHON», а так же официальным дистрибьютором и эксклюзивным представителем в России производителя высокотехнологичных и надежных решений для передачи СВЧ сигналов «FORSTAR».



## JONHON

«JONHON» (основан в 1970 г.)

Разъемы специального, военного и аэрокосмического назначения:

(Применяются в военной, авиационной, аэрокосмической, морской, железнодорожной, горно- и нефтедобывающей отраслях промышленности)

«FORSTAR» (основан в 1998 г.)

ВЧ соединители, коаксиальные кабели,  
кабельные сборки и микроволновые компоненты:

(Применяются в телекоммуникациях гражданского и специального назначения, в средствах связи, РЛС, а так же военной, авиационной и аэрокосмической отраслях промышленности).



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